

US3A THRU US3M

SURFACE MOUNT HIGH EFFICIENCY RECTIFIER

REVERSE VOLTAGE 50 to 1000 Volts FORWARD CURRENT 3.0 Ampere

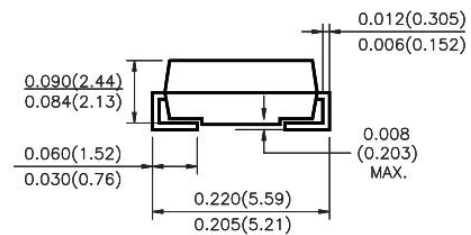
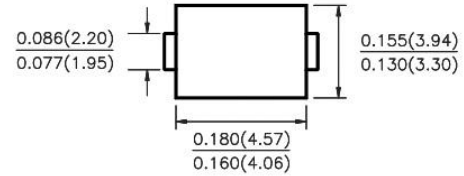
FEATURES

- ◆ Plastic package has underwrites laboratory flammability
- Classification 94V-0
- ◆ Glass Passivated chip junction
- ◆ Built-in strain relief
- ◆ Fast switching speed for high efficiency
- ◆ High temperature soldering: 250°C/10 seconds

Mechanical Data

- ◆ Case: JEDED DO-214AA transfer molded plastic
- ◆ Terminals: Solder plated, solderable per MIL-STD-750, method 2026
- ◆ Polarity: Color band denotes cathode end

SMB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

	SYMBOL	US3A	US3B	US3D	US3G	US3J	US3K	US3M	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current At $T_L=105^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	3.0							Amps
Peak Forward Surge Current 8.3ms single half sine wave superimposed on rated load (JEDEC method)	I_{FSM}	100							Amps
Maximum Instantaneous Forward Voltage at 3.0A	V_F	1.0			1.3	1.7			Volts
Maximum DC Reverse Current $T_A=25^\circ\text{C}$ at rated DC Blocking voltage at $T_A=125^\circ\text{C}$	I_R	10 200							μA
Typical Reverse Recovery Time at $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$	t_{rr}	50				75			nS
Typical Junction Capacitance (Measured at 1.0MHz and applied reverse voltage of 4.0V)	C_J	80				50			pF
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	55							$^\circ\text{C}/\text{W}$
	$R_{\theta JL}$	17							
Operating Junction Temperature	T_J	-55 to +150							$^\circ\text{C}$
Storage Temperature Rang	T_{STG}	-55 to +150							$^\circ\text{C}$

Note: Thermal resistance from Junction to ambient and from junction to lead mounted on P.C.B. with 0.3×0.3”(8.0 × 8.0mm) copper pad areas.

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RATING AND CHARACTERISTIC CURVES US3A THRU US3M

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

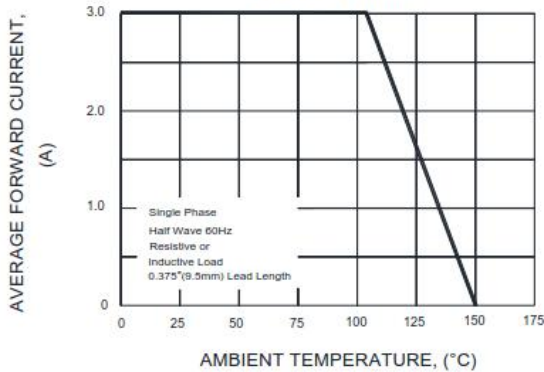


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

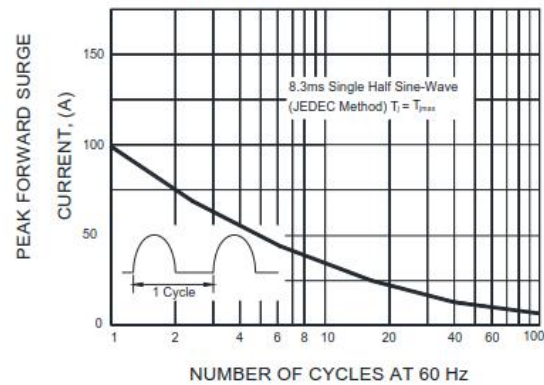


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

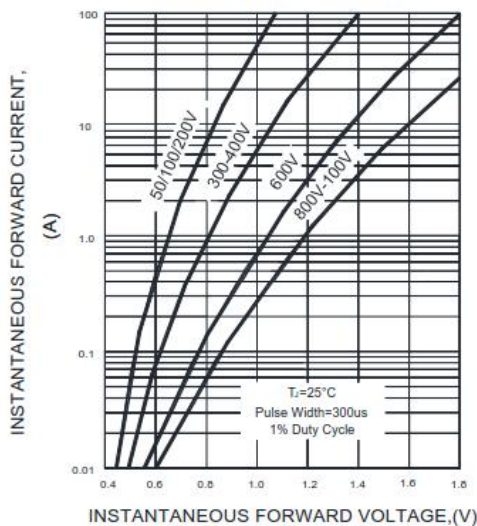


FIG.4-TYPICAL REVERSE CHARACTERISTICS

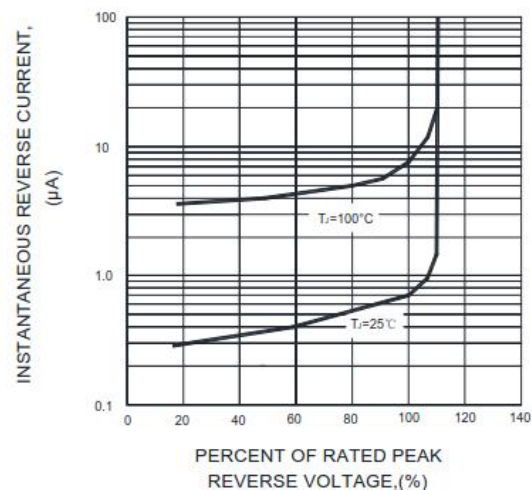


FIG.5-TYPICAL JUNCTION CAPACITANCE

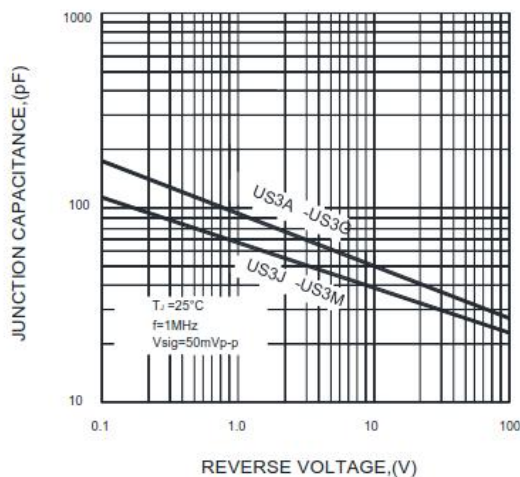
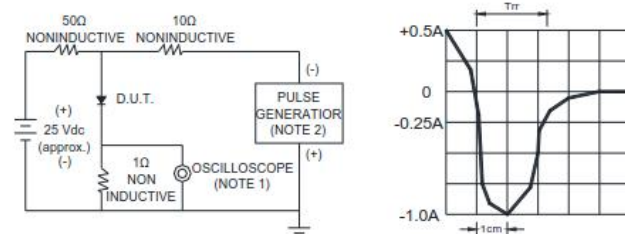


FIG.6-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES : 1. Rise Time=7ns max. Input Impedance= 1 megohm, 22pF
2. Rise time=10ns max. Source Impedance= 50 ohms

SET TIME BASE FOR 50/100ns/cm

Note: Specifications are subject to change without notice. For more detail and update, please visit our website.